

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

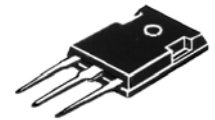
Features

- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * *Pb free*
- * *In compliance with EU RoHs directives*

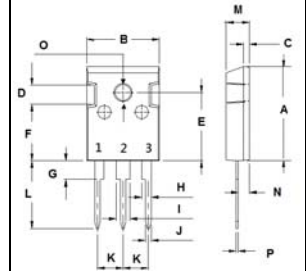


SCHOTTKY BARRIER RECTIFIERS

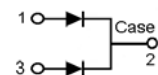
**40 AMPERES
45 VOLTS**



TO-3PS



DIM	MILLIMETERS	
	MIN	MAX
A	19.80	20.20
B	15.45	15.75
C	0.95	1.25
D	3.85	4.15
E	14.15	14.45
F	11.70	12.10
G	3.80	4.20
H	1.80	2.20
I	2.80	3.20
J	1.05	1.35
K	5.26	5.66
L	13.90	14.50
M	4.60	5.00
N	2.35	2.65
O	3.40	3.80
P	0.38	0.62



MAXIMUM RATINGS

Characteristic	Symbol	S40D45CS	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	45	V
RMS Reverse Voltage	$V_{R(RMS)}$	32	V
Average Rectifier Forward Current Total Device (Rated V_R , $T_C=100^\circ\text{C}$)	$I_{F(AV)}$	20 40	A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	40	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I_{FSM}	350	A
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F=20$ Amp $T_C=25^\circ\text{C}$) ($I_F=20$ Amp $T_C=125^\circ\text{C}$)	V_F	---	0.53 0.48	0.57 ---	V
Typical Thermal Resistance junction to case	$R_{\theta jc}$		1.7		$^\circ\text{C}/\text{w}$
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C=25^\circ\text{C}$) (Rated DC Voltage, $T_C=125^\circ\text{C}$)	I_R	---	0.1 50	1.0 ---	mA

FIG-1 FORWARD CURRENT DERATING CURVE

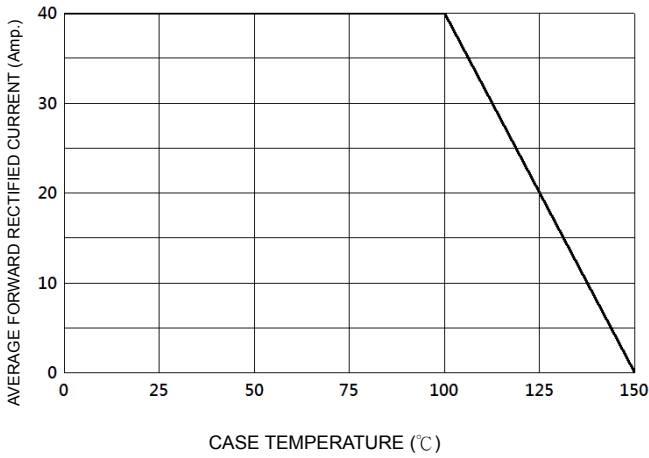


FIG-2 TYPICAL FORWARD CHARACTERISTICS

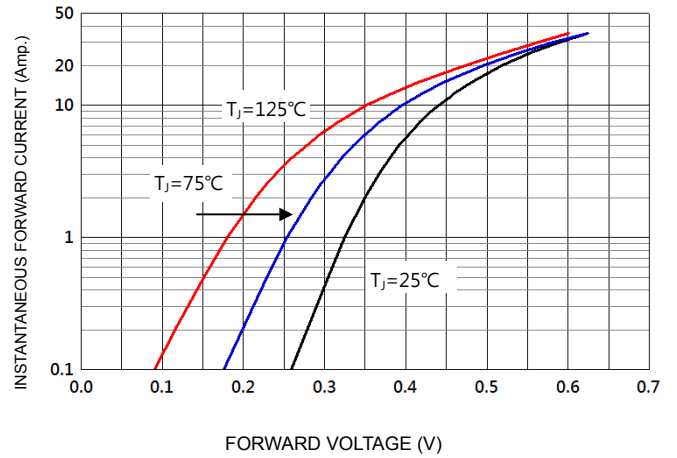


FIG-3 TYPICAL REVERSE CHARACTERISTICS

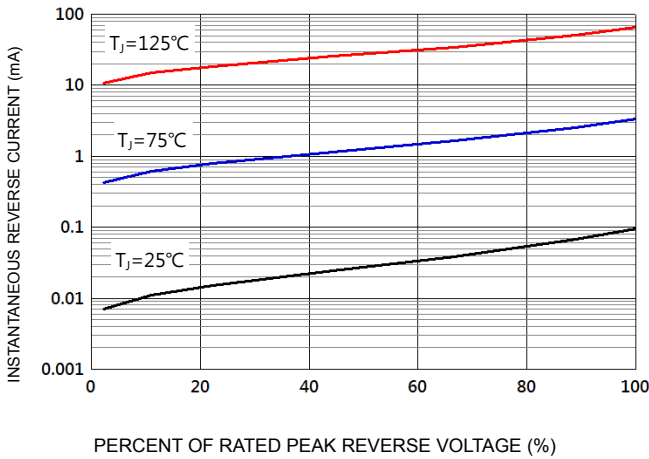


FIG-4 TYPICAL JUNCTION CAPACITANCE

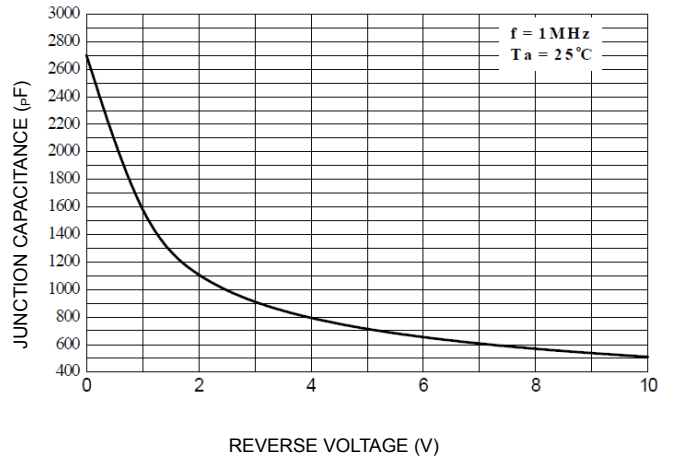
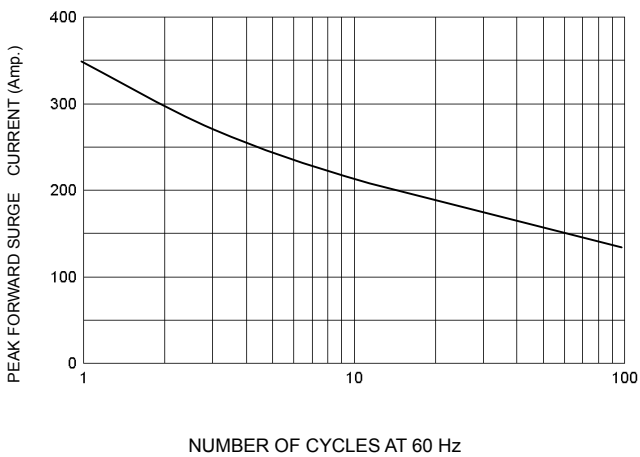


FIG-5 PEAK FORWARD SURGE CURRENT



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